# V20PWM10C

Vishay General Semiconductor

## **High Current Density Surface-Mount** TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.53$  V at  $I_F = 5$  A



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PIN 1 O HEATSINK

click logo to get started.

**DESIGN SUPPORT TOOLS** 



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	20 A			
V <sub>RRM</sub>	100 V			
I <sub>FSM</sub>	150 A			
V <sub>F</sub> at I <sub>F</sub> = 10 A (T <sub>A</sub> = 125 °C)	0.63 V			
T <sub>J</sub> max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Common cathode			

#### **FEATURES**

- · Very low profile typical height of 1.3 mm
- Trench MOS Schottky technology
- Ideal for automated placement
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

### **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V20PWM10C	UNIT	
Device marking code		V20PWM10C			
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	100	V		
Maximum average forward rectified current (Fig. 1)	per device	I <sub>F(AV)</sub> <sup>(1)</sup>	20	А	
	per diode		10	А	
Peak forward surge current 8.3 ms single half sine-wa superimposed on rated load per diode	I <sub>FSM</sub>	150	A		
Operating junction temperature range		T <sub>J</sub> <sup>(2)</sup>	-40 to +175	°C	
Storage temperature range		T <sub>STG</sub>	-55 to +175	°C	

#### Notes

<sup>(1)</sup> With infinite heatsink

 $^{(2)}$  The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{0,JA}$ 



COMPLIANT

HALOGEN

FREE



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 25 °C	V <sub>E</sub> (1)	0.60	-	V	
	I <sub>F</sub> = 10 A			0.74	0.82		
	I <sub>F</sub> = 5.0 A	- T <sub>A</sub> = 125 °C		VF ()	0.53	-	v
	I <sub>F</sub> = 10 A			0.63	0.71		
Reverse current per diode	V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> (2)	0.01	-	- mA	
	$v_{\rm R} = 70$ V	T <sub>A</sub> = 125 °C		1.5	-		
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C		-	0.15		
	v <sub>R</sub> = 100 v	T <sub>A</sub> = 125 °C		3	8		
Typical junction capacitance	4.0 V, 1 MHz		CJ	900	-	pF	

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER SY		V20PWM10C	UNIT		
Typical thermal resistance	R <sub>0JA</sub> (1)(2)	55	°C/W		
	R <sub>0JM</sub> <sup>(3)</sup>	1.8	- C/W		

#### Notes

<sup>(1)</sup> The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

 $^{(2)}$  Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  - junction to ambient

 $^{(3)}$  Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  - junction-to-mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V20PWM10C-M3/I	0.20	I	4500	13" diameter plastic tape and reel		
V20PWM10CHM3/I (1)	0.20	I	4500	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified



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### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

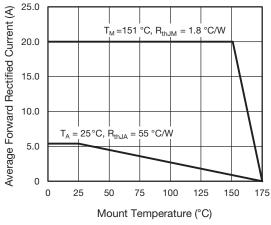


Fig. 1 - Maximum Forward Current Derating Curve

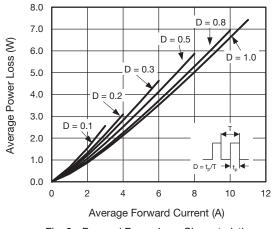


Fig. 2 - Forward Power Loss Characteristics

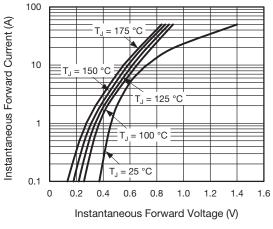


Fig. 3 - Typical Instantaneous Forward Characteristics

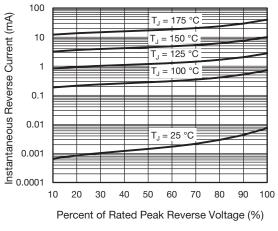


Fig. 4 - Typical Reverse Leakage Characteristics

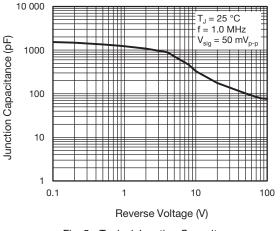


Fig. 5 - Typical Junction Capacitance

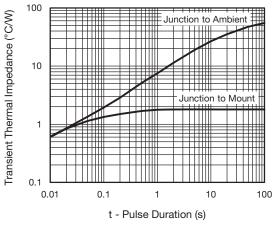


Fig. 6 - Typical Transient Thermal Impedance

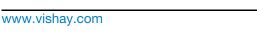
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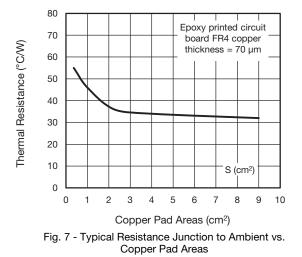
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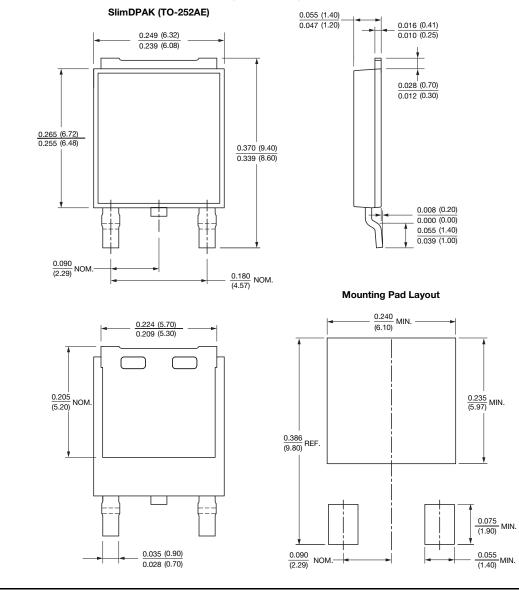


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